



///Oxide///////

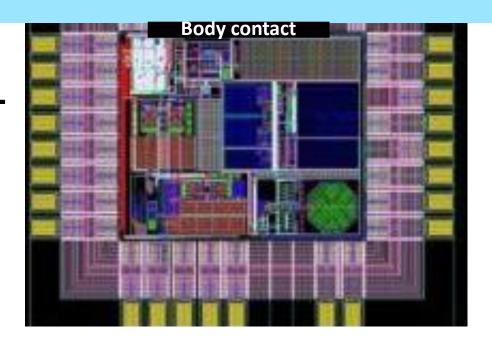
N+ Source

P-type Body

N+ Drain





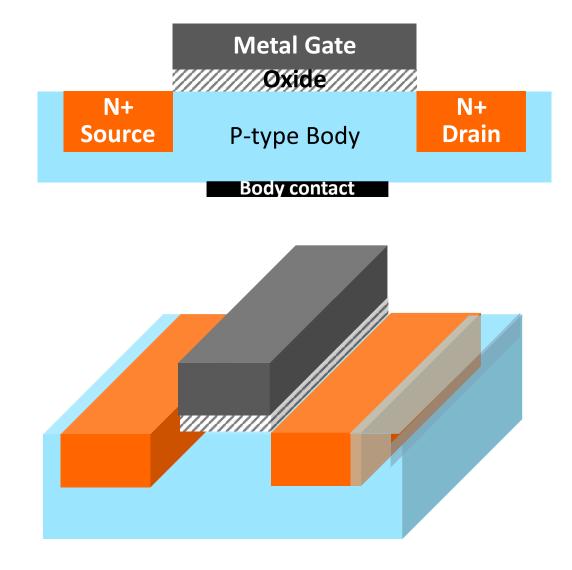


Integrated Circuit Layout Basic

Hanwool Jeong

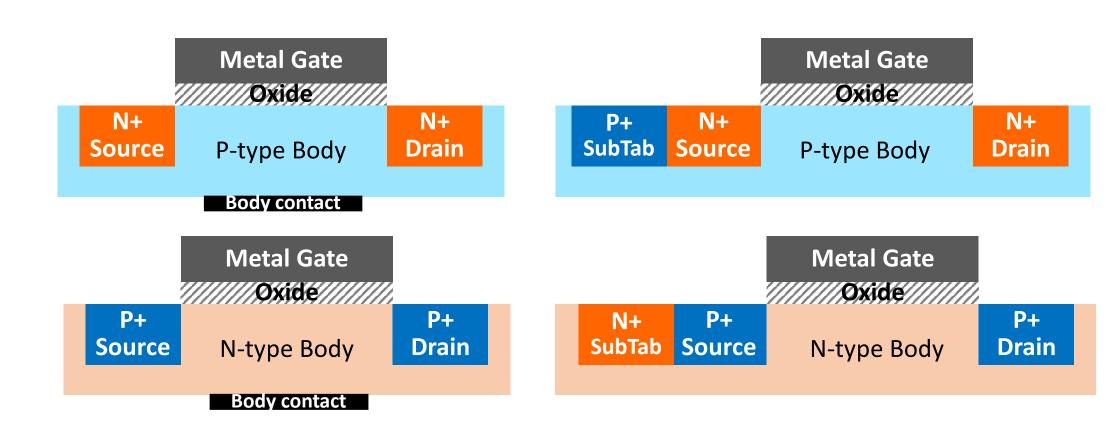
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Revisit NMOSFET Structure



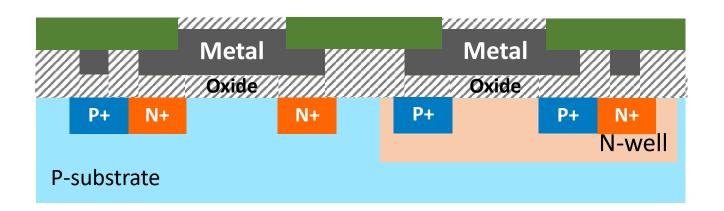
NMOSFET & PMOSFET

Body bias is performed through substrate tab.



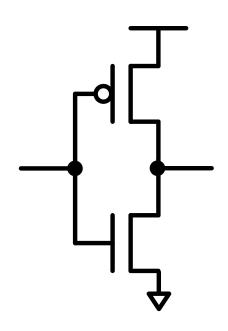
How Would Process Look Like?

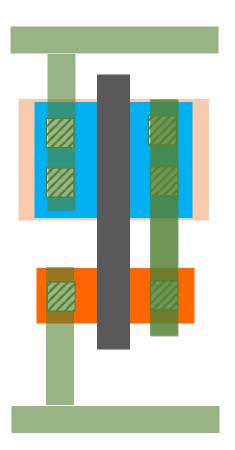
- How can nMOSFET and pMOSFET get together? → N-well
- How can distant be connected? → Metal layer interconnect



How Would Inverter Look Like?

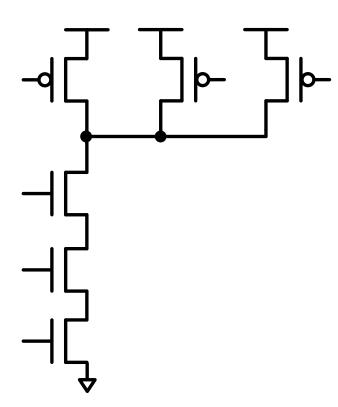
- We will see the top view.
- Assume that body tab is omitted.

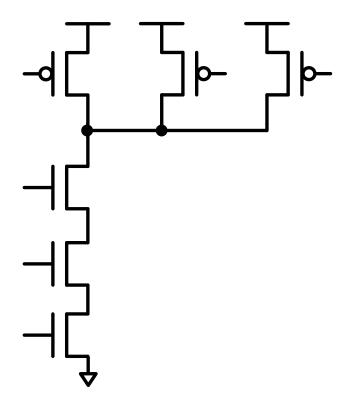




Naïve Drawing 3-input NAND Layout

• If you consider each transistor separately, the resultant layout will be very inefficient.





3-input NAND Layout

- See how diffusions can be shared.
- Compare the parasitic cap in pulldown and pull-up networks

